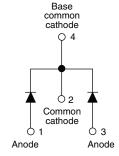


Vishay Semiconductors

Schottky Rectifier, 2 x 6 A



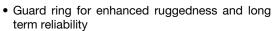


D-PAK	(TO-252AA)
D-FAIL	10-232881

PRODUCT SUMMARY	
Package	D-PAK (TO-252AA)
I _{F(AV)}	2 x 6 A
V_{R}	100 V
V _F at I _F	0.65 V
I _{RM}	4 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	6 mJ

FEATURES

• Low forward voltage drop





Halogen-free according to IEC 61249-2-21 definition

COMPLIANT HALOGEN FREE

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-12CWQ10FN-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	12	Α						
V _{RRM}		100	V						
I _{FSM}	t _p = 5 μs sine	330	Α						
V _F	6 Apk, T _J = 125 °C (per leg)	0.65	V						
TJ	Range	- 55 to 150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-12CWQ10FN-M3	UNITS					
Maximum DC reverse voltage	V_{R}	100	V					
Maximum working peak reverse voltage	V _{RWM}	100	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL TEST CONDITIONS			VALUES	UNITS		
Maximum average per le forward current per device per d		_	50 % duty cycle at T ₂ = 135 °C	rectangular waveform	6	Α		
		I _{F(AV)}	50 % duty cycle at T _C = 135 °C, rectangular waveform		12	^		
Maximum peak one cycle non-repetitive surge current per leg See fig. 7			5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	330	А		
		IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	110			
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6	mJ		
Repetitive avalanche curre	ent per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		1	Α		

VS-12CWQ10FN-M3

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Schottky Rectifier, 2 x 6 A



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Revision: 03-Nov-10

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
		6 A	T _{.1} = 25 °C	0.80	V			
Maximum forward voltage drop per leg See fig. 1	V (1)	12 A	1j=25 C	0.95				
	V _{FM} ⁽¹⁾	6 A	T. ₁ = 125 °C	0.65				
		12 A	1	0.78				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	1	- mA			
See fig. 2		T _J = 125 °C	VR = Nateu VR	4				
Threshold voltage	V _{F(TO)}	T - T movimum		0.47	V			
Forward slope resistance	r _t	ij = ijiiiaxiiiiuiii	$T_J = T_J$ maximum		m $Ω$			
Typical junction capacitance per leg	C _T	V _R = 5 V _{DC} , (test signal ran	183	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	5.0	nH			

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C			
Maximum thermal resistance,	per leg	D	DC operation	3.0	°C/W			
junction to case	per device	R_{thJC}	See fig. 4	1.5	C/VV			
Approximate weight				0.3	g			
Approximate weight				0.01	OZ.			
Marking device			Case style D-PAK (similar to TO-252AA)	12CW(Q10FN			

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 2 x 6 A

Vishay Semiconductors

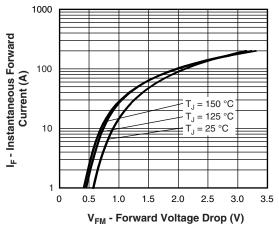


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

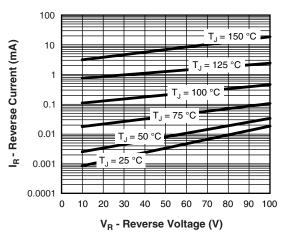


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

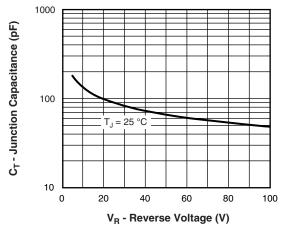


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

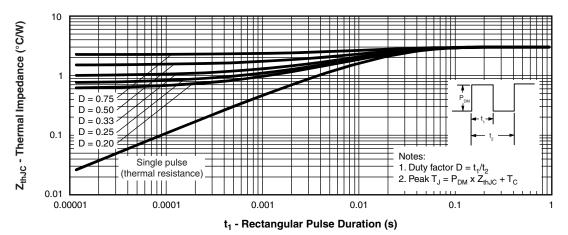


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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Schottky Rectifier, 2 x 6 A



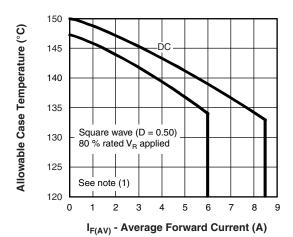


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

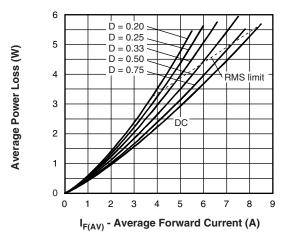


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

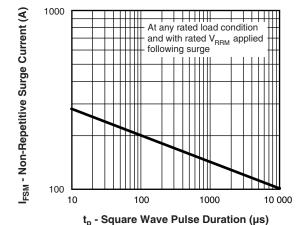


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

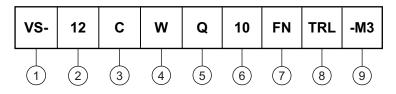


Schottky Rectifier, 2 x 6 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (12 A)
 - Center tap configuration
- 4 Package identifier:

W = D-PAK

- 5 Schottky "Q" series
- 6 Voltage rating (10 = 100 V)
- 7 FN = TO-252AA
- 8 • None = Tube
 - TR = Tape and reel
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-12CWQ10FN-M3	75	3000	Antistatic plastic tube						
VS-12CWQ10FNTR-M3	2000	2000	13" diameter reel						
VS-12CWQ10FNTRL-M3	3000	3000	13" diameter reel						
VS-12CWQ10FNTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					
SPICE model	www.vishay.com/doc?95177					



Vishay Semiconductors

NOTES

3

2

MAX.

0.410

0.070

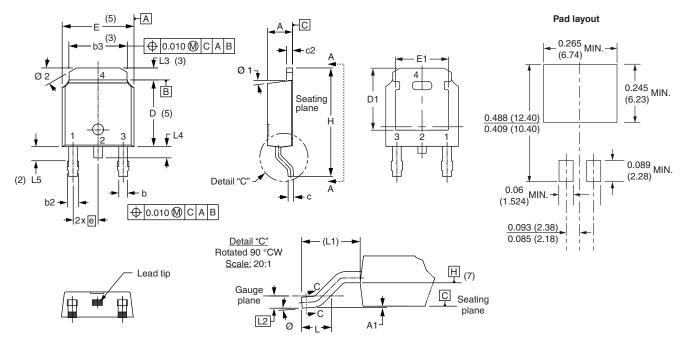
0.050

0.040

0.060

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



Ī	SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES			
	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBUL	MIN.	MAX.	MIN.	MAX	
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41	
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07	
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
ſ	b3	4.95	5.46	0.195	0.215	3		L2	0.51	0.51 BSC		0.020 BSC	
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05	
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04	
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06	
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



Legal Disclaimer Notice

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